



## SAM<sup>TM</sup> Data Sheet SAM-1040-5-800fs-x, $\lambda$ = 1040 nm

 $\lambda = 1040 \text{ nm}$ Laser wavelength

High reflection band  $\lambda = 1000 ... 1060 nm$ 

Absorbance  $A_0 = 5 \%$  $\Delta R = 3 \%$ Modulation depth  $A_{ns} = 2 \%$ Non-saturable loss

 $\Phi_{\text{sat}} = 90 \, \mu\text{J/cm}^2$ Saturation fluence

Relaxation time constant  $\tau = 800 \text{ fs}$ 

 $\Phi = 2 \text{ mJ/cm}^2$ Damage threshold

4.0 mm x 4.0 mm; other dimensions on request Chip area

Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option **x** denotes the type of mounting as follows:

 $\mathbf{x} = 0$ unmounted

glued on a copper heat sink with 12.7 mm  $\varnothing$ x = 12.7 gx = 25.4 gglued on a copper heat sink with 25.4 mm Ø soldered on a copper heat sink with 12.7 mm  $\varnothing$ x = 12.7 ssoldered on a copper heat sink with 25.4 mm  $\varnothing$ x = 25.4 s

x = 25.0 wsoldered on a water cooled Cu-cylinder with 25.0 mm Ø x = FCmounted on a 1 m singlemode fiber cable with FC connector

## Low intensity spectral reflectance

